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PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/655,025	09/05/2003	Martin Hoheisel	32860-000624/US	5214
30596 75	90 08/05/2005		EXAMINER	
HARNESS, DICKEY & PIERCE, P.L.C.			HO, ALLEN C	
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RESTON, VA 20195			ART UNIT	PAPER NUMBER
			2882	
			DATE MAILED: 08/05/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
Office Action Summary		10/655,025	HOHEISEL ET AL.			
		Examiner	Art Unit			
	•	Allen C. Ho	2882			
	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
THE - Exte after - If the - If NC - Failu	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. Insions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. It is period for reply specified above is less than thirty (30) days, a reply of period for reply is specified above, the maximum statutory period were to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from , cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status						
1)⊠	Responsive to communication(s) filed on <u>03 M</u>	lay 2005.				
2a)⊠	This action is FINAL. 2b) This	action is non-final.				
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposit	ion of Claims					
5)□ 6)⊠ 7)⊠	 4) Claim(s) 1-34 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) 1-4,6-28 and 31-34 is/are rejected. 7) Claim(s) 5,29 and 30 is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement. 					
Applicati	ion Papers					
10)⊠	The specification is objected to by the Examine The drawing(s) filed on 11 March 2004 is/are: Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Example 2004.	a) accepted or b) objected to drawing(s) be held in abeyance. See tion is required if the drawing(s) is obj	e 37 CFR 1.85(a). sected to. See 37 CFR 1.121(d).			
Priority ι	ınder 35 U.S.C. § 119	•	•			
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
Attachmen	it(s)					
2) Notice 3) Information	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:				

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1, 3, 7-17, 25, 26, 31, 33, and 34 are rejected under 35 U.S.C. 102(b) as being anticipated by Wei *et al.* (U. S. Patent No. 5,231,655).

With regard to claims 1, 3, 7-14, 16, 17, 25, 26, 31, 33, and 34, Wei et al. disclosed a method for producing and applying at least one of an antiscatter grid and collimator to at least one of an x-ray and gamma detector having a two-dimensional array of detector elements (42) which forms a detector surface with detection regions sensitive to at least one of x-radiation and gamma radiation and less sensitive intermediate regions (Fig. 4(a)), comprising: producing a basic structure (310) using a rapid prototyping technique (the embodiment disclosed by Wei et al. is the prototype or model for the production of actual objects) to form transmission channels (420) and intermediate walls of at least one of the antiscatter grid and collimator; coating the intermediate walls with a material (330) which strongly absorbs at least one of x-radiation and gamma radiation; and applying at least one of the antiscatter grid and collimator to the detector surface (column 5, lines 42 - column 6, line 53).

With regard to claim 15, Wei et al. disclosed the method as claimed in claim 1, wherein the basic structure is constructed so as to produce a focused (20) at least one of antiscatter grid and collimator.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 2, 19-24, and 32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wei et al. (U. S. Patent No. 5,231,655) as applied to claims 1 and 31 above, and further in view of Guru et al. (U. S. Patent No. 6,175,615 B1).

With regard to claims 2, 19-24, and 32, Wei et al. disclosed the method as claimed in claims 1 and 31. However, Wei et al. failed to teach a method of stereolithography is used as the rapid prototyping technique.

Guru *et al.* disclosed a method of stereolithography for prototyping a radiation collimator (column 4, lines 56-61). Guru *et al.* taught that the method of stereolithography permits precise machining and revisions could be easily made for other imaging conditions (column 5, lines 41-48).

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use the method of stereolithography as the prototyping technique, since a person would be motivated to use a prototyping technique that would allow a person to easily

modify the parameters/dimensions of the collimator/grid to custom-fit different imaging

conditions.

5. Claims 6 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wei et

al. (U. S. Patent No. 5,231,655) as applied to claims 1 and 2 above, and further in view of Logan

(U. S. Patent No. 5,418,833).

With regard to claims 6 and 18, Wei et al. disclosed the method as claimed in claim 1 and

2. However, Wei failed to disclose that the coating is performed by at least one of sputtering and

electrolytic deposition.

Logan disclosed that coating could be done by at least one of sputtering and electrolytic

deposition (Logan, column 5, lines 1-5).

It would have been obvious to a person of ordinary skill in the art at the time the

invention was made to coat the intermediate walls using a known process, since a person would

be motivated to use a proven process to coat the intermediate walls without undue

experimentation.

6. Claims 1, 3, 4, 6, 7-18, 25-28, 31, 33, and 34 are rejected under 35 U.S.C. 103(a) as being

unpatentable over Logan (U. S. Patent No. 5,418,833) in view of Wei et al. (U. S. Patent No.

5,231,655).

With regard to claims 1, 3, 7-14, 16, 17, 25, 26, 31, 33, and 34, Logan disclosed a

method, comprising: producing a basic structure (10) using a rapid prototyping technique to form

transmission channels (12) and intermediate walls of at least one of the antiscatter grid and

collimator; coating the intermediate walls with a material (13) which strongly absorbs at least

one of x-radiation and gamma radiation.

However, Logan failed to disclose an x-ray or gamma-ray detector having a two-dimensional array of detector elements, and applying at least one of the antiscatter grid and collimator to the detector surface.

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to employ a digital detector having a two-dimensional array of detector elements, since a person would be motivated to acquire an image in real time.

Wei et al. disclosed applying at least one of the antiscatter grid and collimator to the detector surface (Fig. 4(a)).

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to apply at least one of the antiscatter grid and collimator to the detector surface. As disclosed by Logan, scattered x-rays degrade image quality (column 4, lines 34-48). Accordingly, a person would be motivated to improve image contrast by removing scattered x-rays.

With regard to claims 4, 27, and 28, Logan and Wei et al. disclosed the method as claimed in claim 1, wherein the basic structure is produced from a material which is substantially transparent to at least one of x-radiation and gamma radiation (Logan, column 5, lines 27-30), and end faces of the intermediate walls are kept free of the coating with the absorbent material.

With regard to claims 6 and 18, Logan and Wei et al. disclosed the method as claimed in claim 1 and 2, wherein the coating is performed by at least one of sputtering and electrolytic deposition (Logan, column 5, lines 1-5).

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With regard to claim 15, Logan and Wei et al. disclosed the method as claimed in claim 1, wherein the basic structure is constructed so as to produce a focused (Logan, 22) at least one of antiscatter grid and collimator.

7. Claims 2, 19-24, and 32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Logan (U. S. Patent No. 5,418,833) and Wei *et al.* (U. S. Patent No. 5,231,655) as applied to claims 1 and 31 above, and further in view of Guru *et al.* (U. S. Patent No. 6,175,615 B1).

With regard to claims 2, 19-24, and 32, Logan and Wei et al. disclosed the method as claimed in claims 1 and 31. However, Logan and Wei et al. failed to teach a method of stereolithography is used as the rapid prototyping technique.

Guru *et al.* disclosed a method of stereolithography for prototyping a radiation collimator (column 4, lines 56-61). Guru *et al.* taught that the method of stereolithography permits precise machining and revisions could be easily made for other imaging conditions (column 5, lines 41-48).

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use the method of stereolithography as the prototyping technique, since a person would be motivated to use a prototyping technique that would allow a person to easily modify the parameters/dimensions of the collimator/grid to custom-fit different imaging conditions.

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Allowable Subject Matter

- 8. Claims 5, 29, and 30 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 9. The following is a statement of reasons for the indication of allowable subject matter:

With regard to claims 5, 29, and 30, although the prior art discloses a method as claimed in claim 1, it fails to teach or fairly suggest the steps of producing the basic structure from a material which is substantially transparent to at least one of x-radiation and gamma radiation, and removing the coating from end faces of the intermediate walls as claimed.

Response to Arguments

- 10. Applicant's arguments filed 03 May 2005 with respect to rejection of claims 1-34 under 35 U.S.C. 103(a) as being unpatentable over Souchay *et al.* (U. S. Pub. No. 2003/0081731 A1) in view of Wei *et al.* (U. S. Patent No. 5,231,655) have been fully considered and are persuasive. The rejection of claims 1-34 under 35 U.S.C. 103(a) as being unpatentable over Souchay *et al.* (U. S. Pub. No. 2003/0081731 A1) in view of Wei *et al.* (U. S. Patent No. 5,231,655) has been withdrawn.
- 11. Applicant's arguments filed 03 May 2005 have been fully considered but they are not persuasive.

The applicants argue that Wei et al. and Logan failed to disclose a method that produces at least one of an antiscatter grid and collimator using a "rapid prototyping technique" because the methods disclosed require the removal of material. The examiner respectfully disagrees with

this argument. There is nothing in the claims that excludes a method that requires the removing of material. As noted in MPEP § 2111, during patent examination, claims are given their broadest reasonable interpretation not inconsistent with the specification. It is proper to use the specification to interpret what the applicant meant by a word or phrase recited in the claim. However, it is not proper to read limitation appearing in the specification into the claim when these limitations are not recited in the claim. In the present case, the examiner interprets the "rapid prototyping technique" to mean a technique that produces a prototype or a model for the subsequent working antiscatter grids or collimators. Consequently, any method that produces a structure as recited in the claims would qualify as a "rapid prototyping technique".

For the above reason, the rejections are being maintained.

Conclusion

12. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure:

Mancini (U. S. Patent No. 6,459,771 B1) disclosed a method for fabricating x-ray collimators.

13. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37

CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

however, will the statutory period for reply expire later than SIX MONTHS from the mailing

date of this final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Allen C. Ho whose telephone number is (571) 272-2491. The

examiner can normally be reached on Monday - Friday from 8:00 am - 5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Edward J. Glick can be reached at (571) 272-2490. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Allen C. Ho

Primary Examiner

allen C. Ho

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